## NSN 5961-01-078-8500

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Inclosure Material:
Metal
Overall Length:
1.040 inches
Overall Diameter:
2.250 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1600.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
350.00 amperes forward current, total rms universal
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
2 uninsulated wire lead w/terminal lug and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0